

## N-Channel 30-V (D-S) MOSFET

### Key Features:

- Low  $r_{DS(on)}$  trench technology
- Low thermal impedance
- Fast switching speed

### Typical Applications:

- DC/DC Conversion
- Power Routing
- Motor Drives

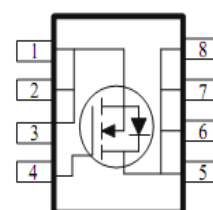
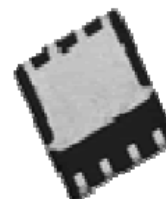
### PRODUCT SUMMARY

$V_{DS}$ (V)	$r_{DS(on)}$ (m $\Omega$ )	$I_D$ (A)
30	2.8 @ $V_{GS} = 10V$	35
	4.8 @ $V_{GS} = 4.5V$	26

DFN5X6-8L



RoHS  
COMPLIANT  
HALOGEN  
FREE



### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)

Parameter	Symbol	Limit	Units
Drain-Source Voltage	$V_{DS}$	30	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	
Continuous Drain Current <sup>a</sup>	$I_D$	35	A
		28	
Pulsed Drain Current <sup>b</sup>	$I_{DM}$	120	
Continuous Source Current (Diode Conduction) <sup>a</sup>	$I_S$	7.3	A
Power Dissipation <sup>a</sup>	$P_D$	5	W
		3.2	
Operating Junction and Storage Temperature Range	$T_J, T_{stg}$	-55 to 150	$^\circ\text{C}$

### THERMAL RESISTANCE RATINGS

Parameter	Symbol	Maximum	Units
Maximum Junction-to-Ambient <sup>a</sup>	$R_{\theta JA}$	25	$^\circ\text{C/W}$
		65	

### Notes

- Surface Mounted on 1" x 1" FR4 Board.
- Pulse width limited by maximum junction temperature

## Electrical Characteristics

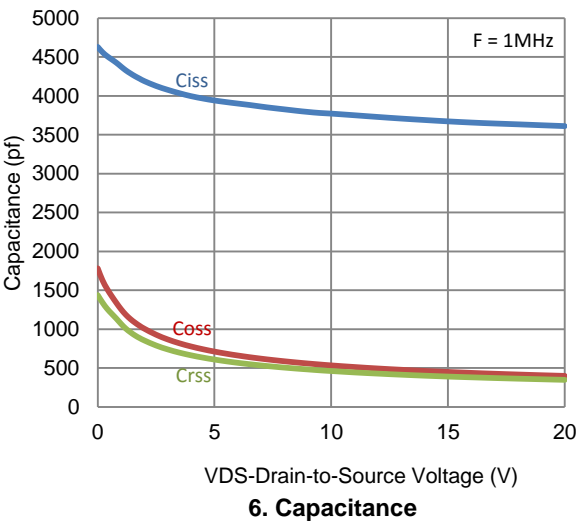
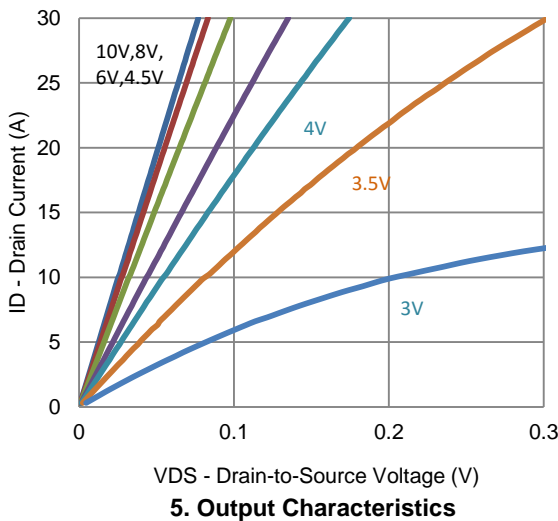
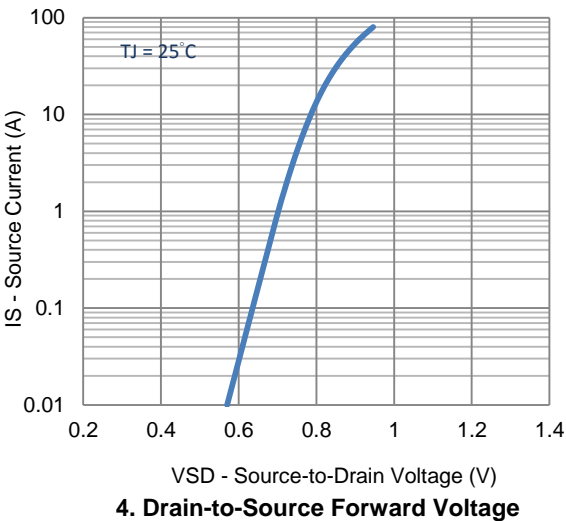
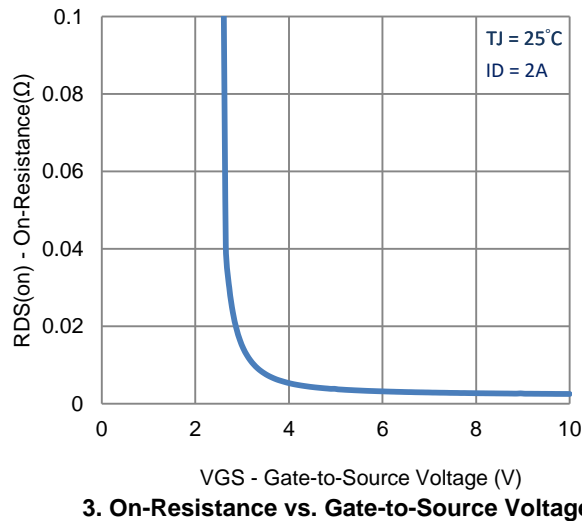
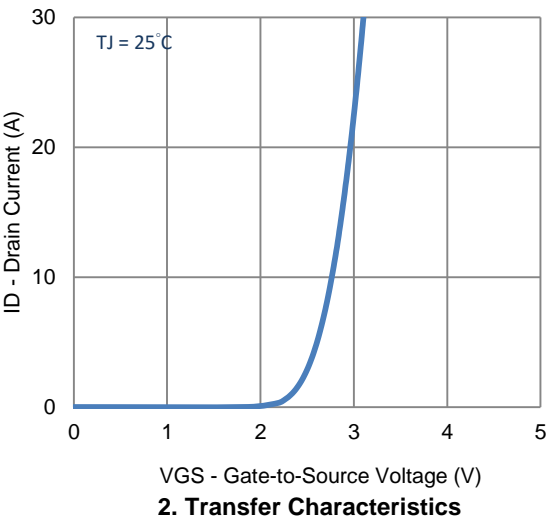
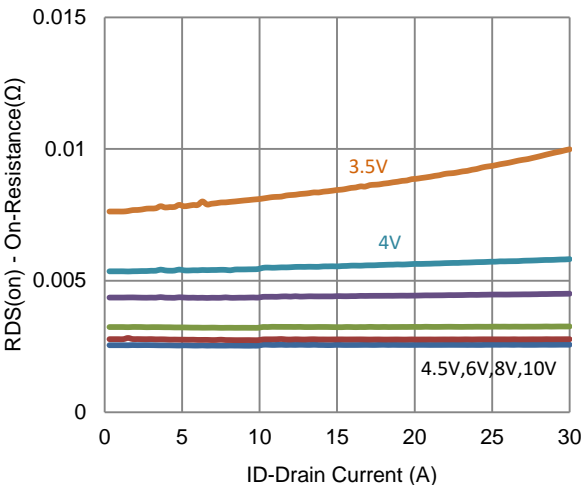
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
<b>Static</b>						
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	1			V
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0 V$ , $V_{GS} = \pm 20 V$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 24 V$ , $V_{GS} = 0 V$			1	uA
		$V_{DS} = 24 V$ , $V_{GS} = 0 V$ , $T_J = 55^\circ C$			10	
On-State Drain Current <sup>a</sup>	$I_{D(on)}$	$V_{DS} = 5 V$ , $V_{GS} = 10 V$	50			A
Drain-Source On-Resistance <sup>a</sup>	$r_{DS(on)}$	$V_{GS} = 10 V$ , $I_D = 20 A$			2.8	mΩ
		$V_{GS} = 4.5 V$ , $I_D = 18 A$			4.8	
Forward Transconductance <sup>a</sup>	$g_{fs}$	$V_{DS} = 15 V$ , $I_D = 20 A$		82		S
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	$I_S = 3.7 A$ , $V_{GS} = 0 V$		0.75		V
<b>Dynamic <sup>b</sup></b>						
Total Gate Charge	$Q_g$	$V_{DS} = 15 V$ , $V_{GS} = 4.5 V$ , $I_D = 2 A$		35		nC
Gate-Source Charge	$Q_{gs}$			10		
Gate-Drain Charge	$Q_{gd}$			12		
Turn-On Delay Time	$t_{d(on)}$	$V_{DS} = 15 V$ , $R_L = 7.5 \Omega$ , $I_D = 2 A$ , $V_{GEN} = 10 V$ , $R_{GEN} = 6 \Omega$		7		ns
Rise Time	$t_r$			18		
Turn-Off Delay Time	$t_{d(off)}$			95		
Fall Time	$t_f$			35		
Input Capacitance	$C_{iss}$	$V_{DS} = 15 V$ , $V_{GS} = 0 V$ , $f = 1 Mhz$		3671		pF
Output Capacitance	$C_{oss}$			449		
Reverse Transfer Capacitance	$C_{rss}$			390		

## Notes

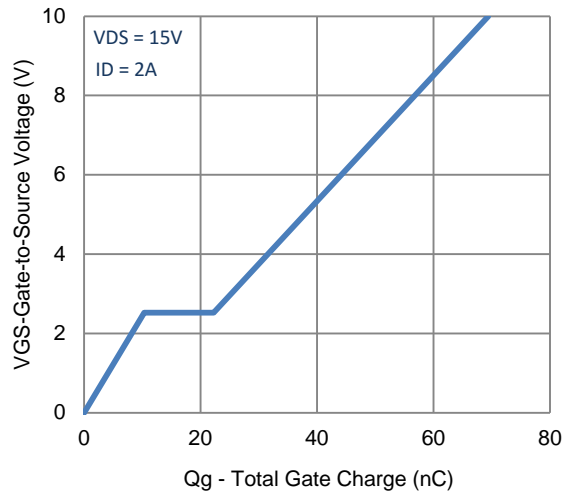
- a. Pulse test:  $PW \leq 300 \mu s$  duty cycle  $\leq 2\%$ .
- b. Guaranteed by design, not subject to production testing.

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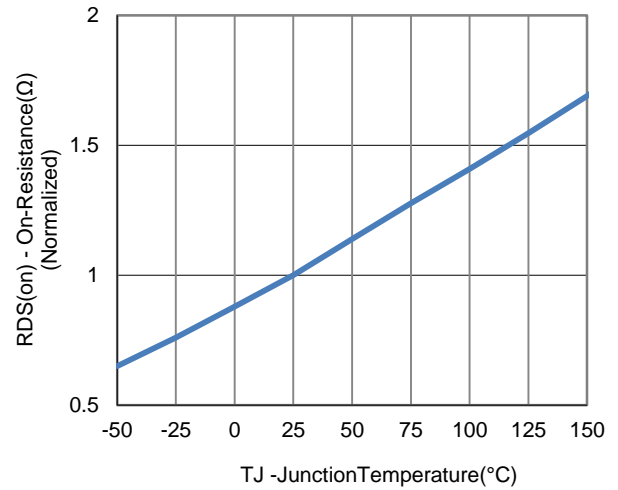
Typical Electrical Characteristics



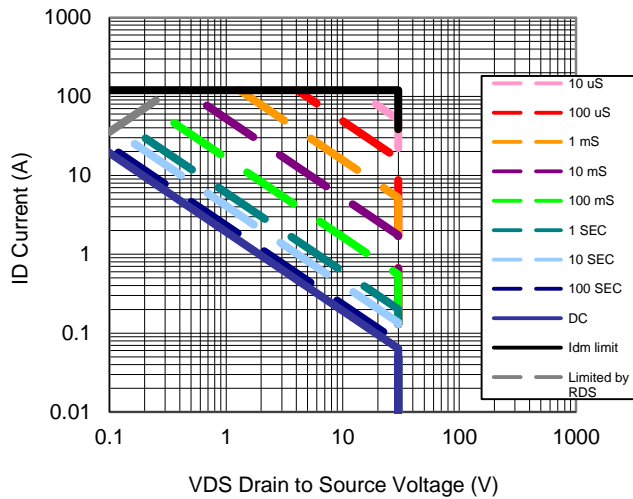
## Typical Electrical Characteristics



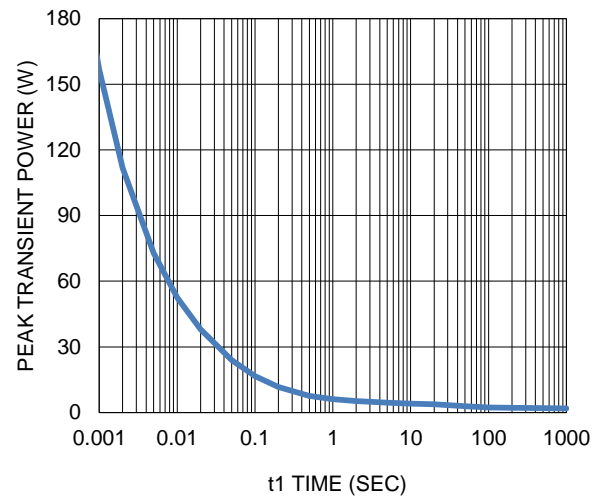
7. Gate Charge



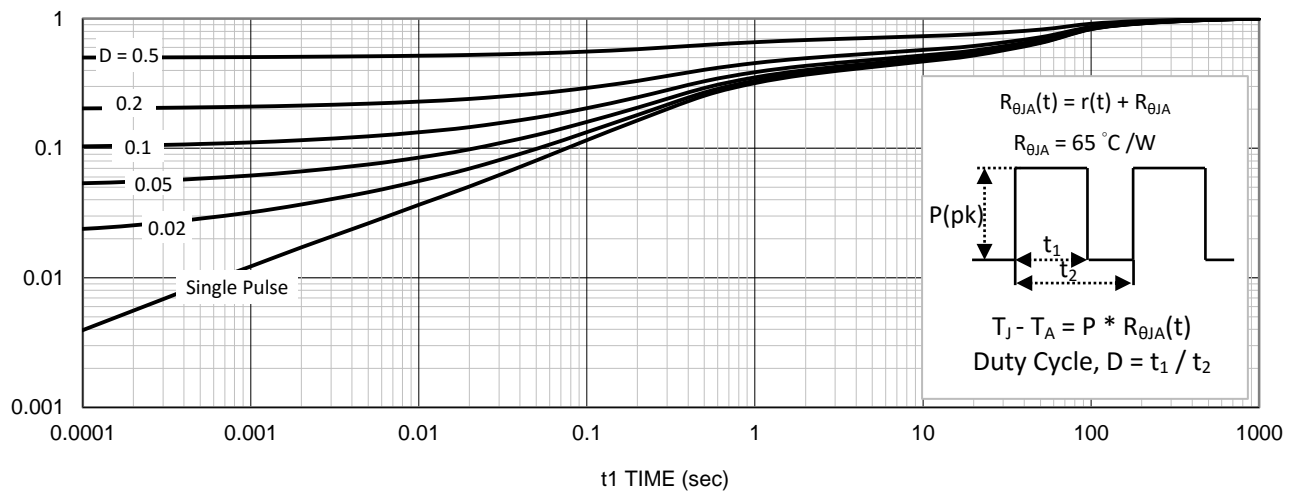
8. Normalized On-Resistance Vs Junction Temperature



9. Safe Operating Area

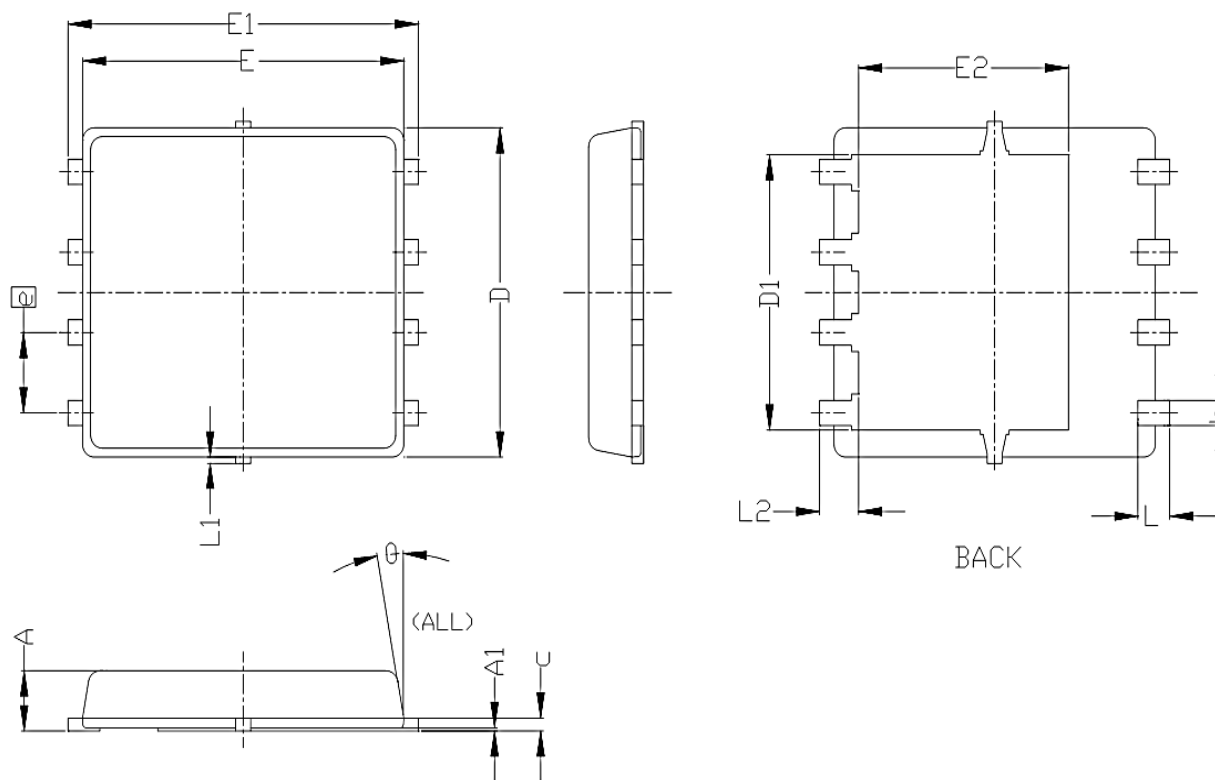


10. Single Pulse Maximum Power Dissipation



11. Normalized Thermal Transient Junction to Ambient

## Package Information



SYMBOLS	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.85	0.95	1.00	0.033	0.037	0.039
A1	0.00	—	0.05	0.000	—	0.002
b	0.30	0.40	0.50	0.012	0.016	0.020
c	0.15	0.20	0.25	0.006	0.008	0.010
D	5.20 BSC			0.205 BSC		
D1	4.35 BSC			0.171 BSC		
E	5.55 BSC			0.219 BSC		
E1	6.05 BSC			0.238 BSC		
E2	3.62 BSC			0.143 BSC		
e	1.27 BSC			0.050 BSC		
L	0.45	0.55	0.65	0.018	0.022	0.026
L1	0	—	0.15	0	—	0.006
L2	0.68 REF			0.027 REF		
θ	0°	—	10°	0°	—	10°